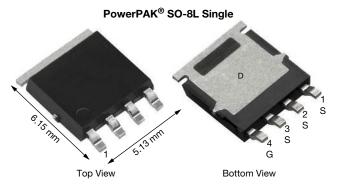
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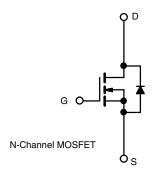
Automotive N-Channel 100 V (D-S) 175 °C MOSFET



$\begin{tabular}{|c|c|c|c|} \hline PRODUCT SUMMARY \\ \hline V_{DS} (V) & 100 \\ \hline R_{DS(on)} (\Omega) \mbox{ at } V_{GS} = 10 \ V & 0.0210 \\ \hline R_{DS(on)} (\Omega) \mbox{ at } V_{GS} = 4.5 \ V & 0.0258 \\ \hline I_D (A) & 42 \\ \hline Configuration & Single \\ \hline \end{tabular}$

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified ^d
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





HALOGEN

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ488EP (for detailed order number please see <u>www.vishay.com/doc?79771</u>)

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	s otherwise notec)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	100	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current	T _C = 25 °C ª	I	42		
	T _C = 125 °C	ID	24		
Continuous source current (diode conduction) a	l	IS	60	А	
Pulsed drain current ^b	I _{DM}	170			
Single pulse avalanche current	L = 0.1 mH	I _{AS}	5.8		
Single pulse avalanche energy		E _{AS}	1.68	mJ	
Martin and the line b	T _C = 25 °C	D	83	W	
Maximum power dissipation ^b	T _C = 125 °C	PD	27	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (Peak temperature	e, f		260	0	

THERMAL RESISTANCE RATINGS

I RENMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	65	°C/W
Junction-to-case (drain)		R _{thJC}	1.8	C/W

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR-4 material)
- d. Parametric verification ongoing
- See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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SQJ488EP

PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static							•	
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		100	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	1.5	2.0	2.5	v	
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 100 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA	
		$V_{GS} = 0 V$	$V_{DS} = 100 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150		
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	30	-	-	Α	
		$V_{GS} = 10 V$	I _D = 7.1 A	-	0.0176	0.0210		
Drain aquiras en stata registance à	Р	$V_{GS} = 4.5 V$	I _D = 6.4 A	-	0.0215	0.0258		
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}$	I _D = 7.1 A, T _J = 125 °C	-	-	0.0360	Ω	
		$V_{GS} = 10 V$	I _D = 7.1 A, T _J = 175 °C	-	-	0.0450		
Forward transconductance b	g _{fs}	V _{DS}	= 15 V, I _D = 7.1 A	-	28	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			-	782	978		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 50 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	372	462	pF	
Reverse transfer capacitance	C _{rss}			-	44	55		
Total gate charge ^c	Qg			-	18	27		
Gate-source charge	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, \text{ I}_{D} = 15 \text{ A}$	-	2	-	nC	
Gate-drain charge ^c	Q _{gd}			-	4.7	-		
Gate resistance	Rg	f = 1 MHz		1.1	2.2	3.3	Ω	
Turn-on delay time ^c	t _{d(on)}			-	4	6		
Rise time ^c	t _r	$V_{DD} = 50 \text{ V, } \text{R}_{\text{L}} = 5 \ \Omega$ $\text{I}_{\text{D}} \cong 1 \text{ A, } \text{V}_{\text{GEN}} = 10 \text{ V, } \text{R}_{\text{g}} = 6 \ \Omega$		-	11	16	ns	
Turn-off delay time ^c	t _{d(off)}			-	20	30		
Fall time ^c	t _f	1		-	4.6	7		
Source-Drain Diode Ratings and Cha	racteristics ^b							
Pulsed current ^a	I _{SM}			-	-	128	Α	
Forward voltage	V _{SD}	I _F :	= 4.7 A, V _{GS} = 0	-	0.78	1.2	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2

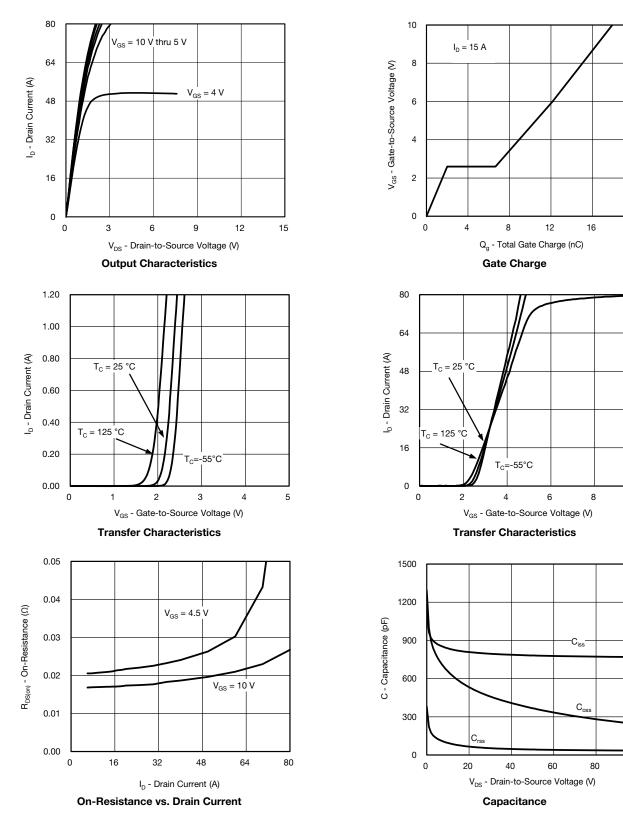


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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



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3

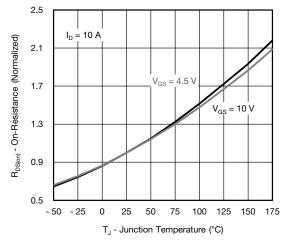
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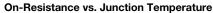
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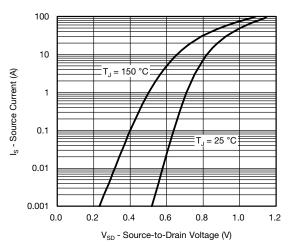


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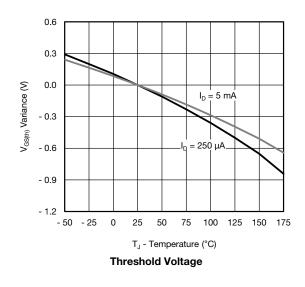
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

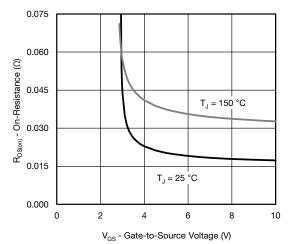




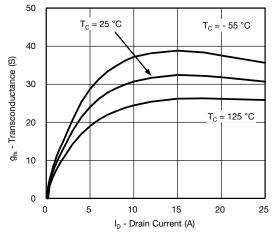


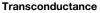
Source Drain Diode Forward Voltage

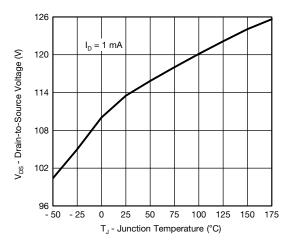




On-Resistance vs. Gate-to Source Voltage







Drain Source Breakdown vs. Junction Temperature

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4

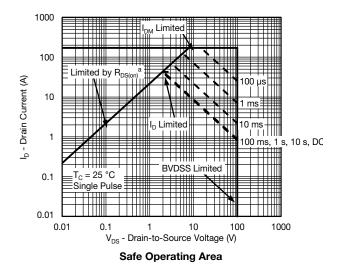
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



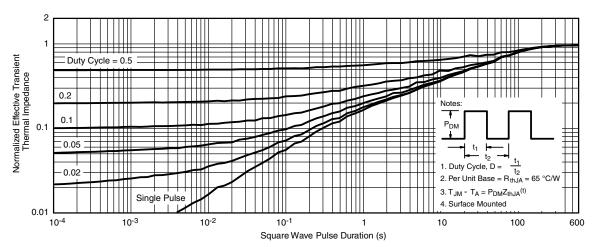
Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

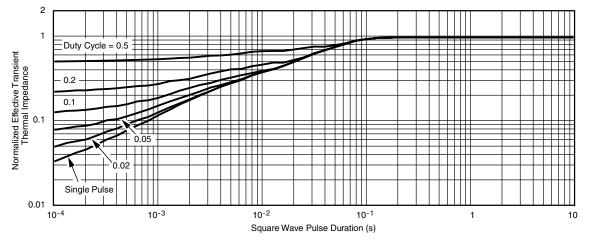


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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

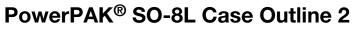
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

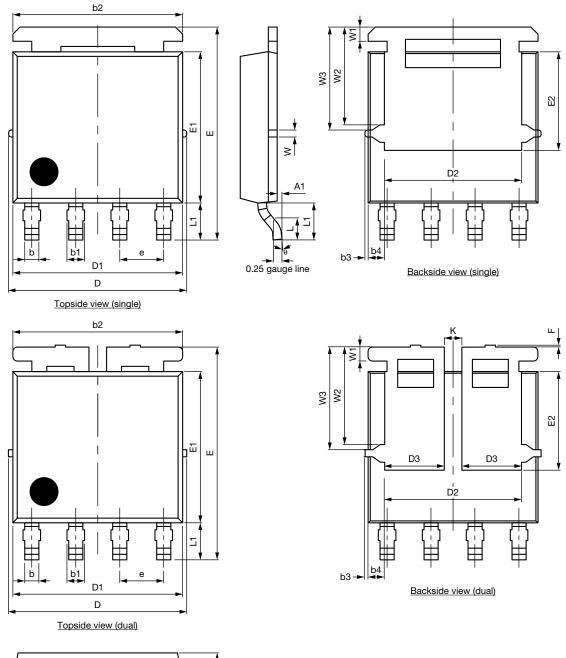
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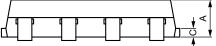
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Package Information



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DIM.		MILLIMETERS			INCHES			
	MIN.	MIN. NOM. MAX.			MIN. NOM. MA			
А	1.00	1.07	1.14	0.039	0.042	0.045		
A1	0.00	-	0.127	0.00	-	0.005		
b	0.33	0.41	0.48	0.013	0.016	0.019		
b1	0.44	0.51	0.58	0.017	0.020	0.023		
b2	4.80	4.90	5.00	0.189	0.193	0.197		
b3		0.094			0.004			
b4		0.47			0.019			
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	5.00	5.13	5.25	0.197	0.202	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D3	1.63	1.73	1.83	0.064	0.068	0.072		
е		1.27 BSC		0.050 BSC				
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	2.75	2.85	2.95	0.108	0.112	0.116		
F	-	-	0.15	-	-	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
К		0.51			0.020			
W		0.23			0.009			
W1	0.41			0.016				
W2	2.82			0.111				
W3		2.96			0.117			
θ	0°	-	10°	0°	-	10°		

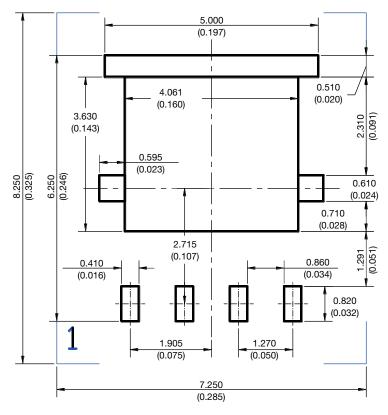
Note

• Millimeters will govern



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RECOMMENDED MINIMUM PAD FOR PowerPAK[®] SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)

Revision: 07-Feb-12



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